MMIC wideband amplifier

Rev. 3 — 13 July 2015

Product data sheet

1. Product profile

1.1 General description

Silicon Monolithic Microwave Integrated Circuit (MMIC) wideband amplifier with internal matching circuit in a 6-pin SOT363 plastic SMD package.

1.2 Features and benefits

- Internally matched to 50 Ω
- A gain of 31.1 dB at 500 MHz
- Output power at 1 dB gain compression = 4 dBm
- Supply current = 16.0 mA at a supply voltage of 2.5 V
- Reverse isolation > 52 dB up to 750 MHz
- Good linearity with low second order and third order products
- Noise figure = 3.2 dB at 500 MHz
- Unconditionally stable (K > 1)
- No output inductor required

1.3 Applications

- LNB IF amplifiers
- General purpose low noise wideband amplifier for frequencies between DC and 750 MHz

2. Pinning information

Pin	Description	Simplified outline	Graphic symbol
1	V _{CC}		
2, 5	GND2		
3	RF_OUT		6
4	GND1		
6	RF_IN		4 2, 5 777 777 sym052



3. Ordering information

Table 2. Ordering information							
Type number Package							
	Name	Description	Version				
BGA2870	-	plastic surface-mounted package; 6 leads	SOT363				

4. Marking

Table 3. Marking					
Type number	Marking code	Description			
BGA2870	YC*	* = - : made in Hong Kong			
		* = p : made in Hong Kong			
		* = W : made in China			
		* = t : made in Malaysia			

5. Limiting values

Table 4.Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
V _{CC}	supply voltage	RF input AC coupled	-0.5	3.6	V
I _{CC}	supply current		-	55	mA
P _{tot}	total power dissipation	T _{sp} = 90 °C	-	200	mW
T _{stg}	storage temperature		-40	+125	°C
Tj	junction temperature		-	125	°C
P _{drive}	drive power		-	+10	dBm

6. Thermal characteristics

Table 5.	Thermal characteristics						
Symbol	Parameter	Conditions	Тур	Unit			
R _{th(j-sp)}	thermal resistance from junction to solder point	P_{tot} = 200 mW; T_{sp} = 90 °C	300	K/W			

7. Characteristics

Table 6.Characteristics

 $V_{CC} = 2.5 V; Z_S = Z_L = 50 \Omega; P_i = -30 dBm; T_{amb} = 25 °C; measured on demo board; unless otherwise specified.$

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CC}	supply voltage		2.3	2.5	2.7	V
I _{CC}	supply current		13.5	16.0	17.1	mA

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
G _p	power gain	f = 250 MHz	30.6	31.2	31.8	dB
		f = 500 MHz	30.5	31.1	31.7	dB
		f = 750 MHz	30.3	31.0	31.7	dB
RL _{in}	input return loss	f = 250 MHz	25	27	29	dB
		f = 500 MHz	20	22	24	dB
		f = 750 MHz	15	16	18	dB
RL _{out}	output return loss	f = 250 MHz	12	17	21	dB
		f = 500 MHz	12	17	21	dB
		f = 750 MHz	14	15	16	dB
ISL	isolation	f = 250 MHz	50	70	91	dB
		f = 500 MHz	40	60	80	dB
		f = 750 MHz	51	52	105	dB
NF	noise figure	f = 250 MHz	2.6	3.1	3.6	dB
		f = 500 MHz	2.8	3.2	3.7	dB
		f = 750 MHz	3.3	3.7	4.1	dB
B _{-3dB}	-3 dB bandwidth	3 dB below gain at 1 GHz	1.9	2.1	2.3	GHz
К	Rollett stability factor	f = 250 MHz	29	44	60	
		f = 500 MHz	9	14	18	
		f = 750 MHz	5	6	7	
P _{L(sat)}	saturated output power	f = 250 MHz	5	5	6	dBm
		f = 500 MHz	4	4	5	dBm
		f = 750 MHz	3	4	5	dBm
P _{L(1dB)}	output power at 1 dB gain compression	f = 250 MHz	4	5	5	dBm
		f = 500 MHz	3	4	5	dBm
		f = 750 MHz	2	4	5	dBm
IP3 _I	input third-order intercept point	$P_{drive} = -35 dBm$ (for each tone)				_
		f ₁ = 250 MHz; f ₂ = 251 MHz	-18	-16	-14	dBm
		f ₁ = 500 MHz; f ₂ = 501 MHz	-19	-17	-15	dBm
		f ₁ = 750 MHz; f ₂ = 751 MHz	-20	-18	-16	dBm
IP3 ₀	output third-order intercept point	$P_{drive} = -35 dBm$ (for each tone)				_
		f ₁ = 250 MHz; f ₂ = 251 MHz	13	15	17	dBm
		f ₁ = 500 MHz; f ₂ = 501 MHz	12	14	16	dBm
		f ₁ = 750 MHz; f ₂ = 751 MHz	11	13	15	dBm
P _{L(2H)}	second harmonic output power	$P_{drive} = -35 \text{ dBm}$				-
× /		f _{1H} = 250 MHz; f _{2H} = 500 MHz	-38	-36	-34	dBm
		f _{1H} = 500 MHz; f _{2H} = 1900 MHz	-38	-36	-34	dBm
∆IM2	second-order intermodulation distance	$P_{drive} = -35 \text{ dBm}$ (for each tone)				
		f ₁ = 250 MHz; f ₂ = 251 MHz	25	27	29	dBc
		$f_1 = 500 \text{ MHz}; f_2 = 501 \text{ MHz}$	22	24	26	dBc

Table 6.Characteristics ...continued $V_{co} = 2.5 V$ $Z_s = Z_i = 50 \Omega$ $P_i = -30 dBm$ T_{ar}

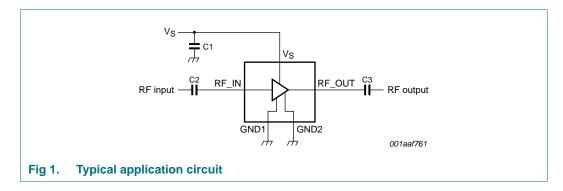
- 25 °C: measured on demo board: unless otherwise specified

8. Application information

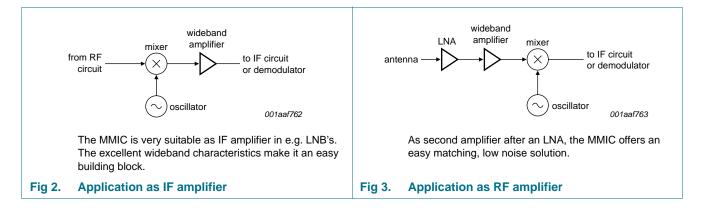
<u>Figure 1</u> shows a typical application circuit for the BGA2870 MMIC. The device is internally matched to 50 Ω , and therefore does not need any external matching. The value of the input and output DC blocking capacitors C2 and C3 should not be more than 100 pF for applications above 100 MHz. However, when the device is operated below 100 MHz, the capacitor value should be increased.

The 22 nF supply decoupling capacitor C1 should be located as close as possible to the MMIC.

The PCB top ground plane, connected to pins 2, 4 and 5 must be as close as possible to the MMIC, preferably also below the MMIC. When using via holes, use multiple via holes as close as possible to the MMIC.

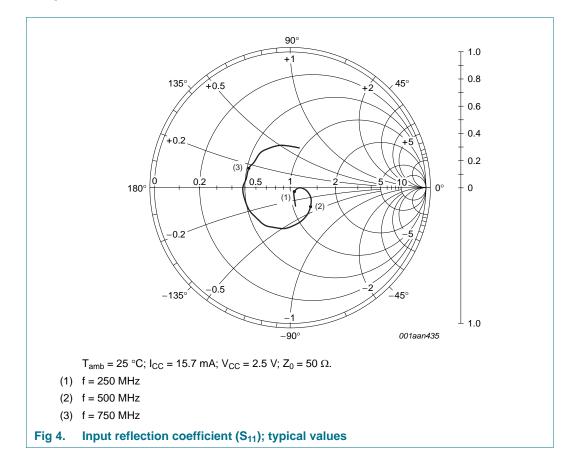


8.1 Application examples

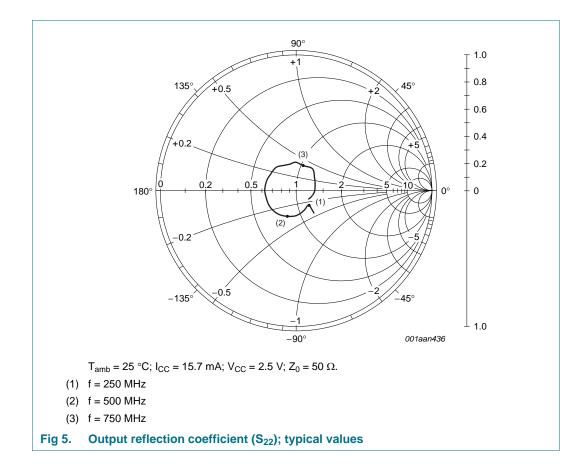


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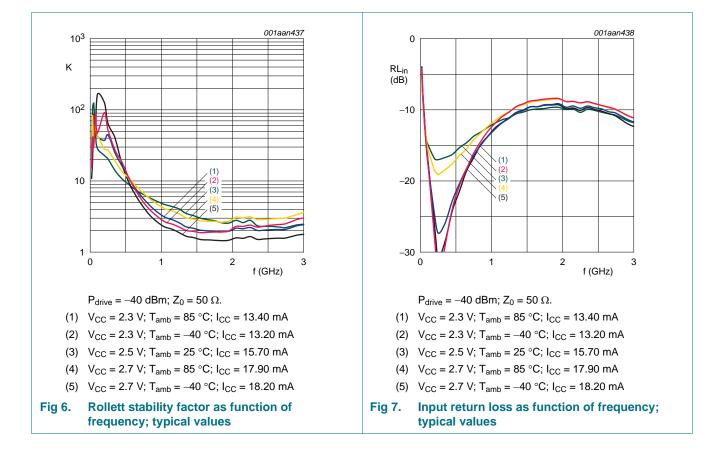
8.2 Graphs



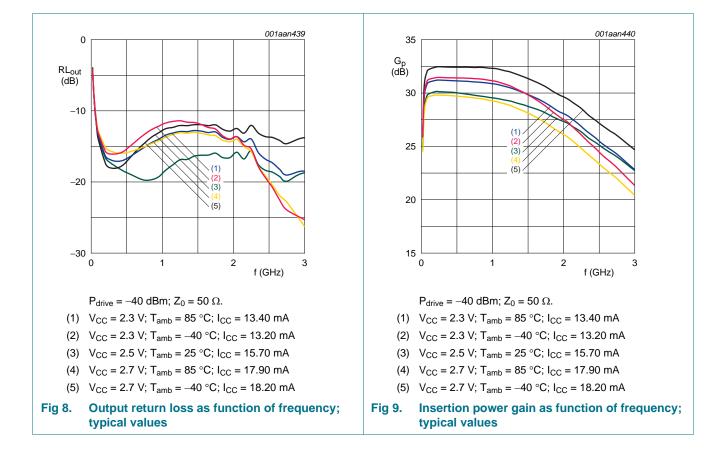
MMIC wideband amplifier



MMIC wideband amplifier



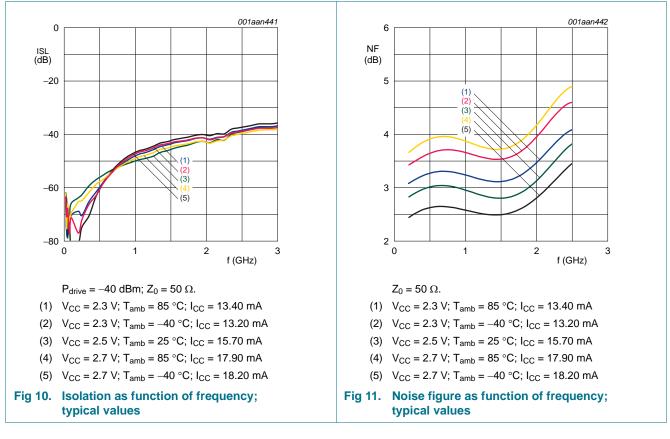
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8.3 Tables

Table 7.Supply current over temperature and supply voltagesTypical values.

Symbol	Parameter	Conditions	T _{amb} (°0	T _{amb} (°C)			
			-40	25	85		
I _{CC} supply current	supply current	V _{CC} = 2.3 V	13.20	13.30	13.40	mA	
	$V_{CC} = 2.5 V$	15.80	15.70	15.70	mA		
		$V_{CC} = 2.7 V$	18.20	18.00	17.90	mA	

Table 8.Second harmonic output power over temperature and supply voltagesTypical values.

Symbol	Parameter	Conditions	T _{amb} (°C)		Unit	
			-40	25	85	
P _{L(2H)}	second harmonic output power	f = 250 MHz; P_{drive} = -35 dBm				
		$V_{CC} = 2.3 V$	-42	-37	-36	dBm
		$V_{CC} = 2.5 V$	-38	-36	-35	dBm
		$V_{CC} = 2.7 V$	-37	-36	-35	dBm
		f = 500 MHz; P_{drive} = -35 dBm				
		V _{CC} = 2.3 V	-42	-38	-35	dBm
		V _{CC} = 2.5 V	-38	-36	-34	dBm
		V _{CC} = 2.7 V	-36	-35	-33	dBm

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Symbol	Parameter	Conditions	T _{amb} (Unit	
			-40	25	85	
P _{i(1dB)}	input power at 1 dB gain compression	f = 250 MHz				
		$V_{CC} = 2.3 V$	-27	-26	-26	dBm
		$V_{CC} = 2.5 V$	-26	-26	-26	dBm
		$V_{CC} = 2.7 V$	-26	-25	-25	dBm
		f = 500 MHz				
		V _{CC} = 2.3 V	-27	-26	-27	dBm
		$V_{CC} = 2.5 V$	-27	-26	-26	dBm
		$V_{CC} = 2.7 V$	-27	-26	-26	dBm
		f = 750 MHz				
		V _{CC} = 2.3 V	-27	-26	-27	dBm
		$V_{CC} = 2.5 V$	-27	-27	-27	dBm
		$V_{CC} = 2.7 V$	-27	-26	-27	dBm

 Table 9.
 Input power at 1 dB gain compression over temperature and supply voltages

 Typical values.

Table 10.	Output power at 1 dB gain compression over temperature and supply voltages
Typical valu	Ies.

Symbol	Parameter	Conditions	T _{amb} (°C)			Unit
			-40	25	85	
P _{L(1dB)}	output power at 1 dB gain compression	f = 250 MHz				
		$V_{CC} = 2.3 V$	3	3	3	dBm
		$V_{CC} = 2.5 V$	4	5	4	dBm
		$V_{CC} = 2.7 V$	6	6	5	dBm
		f = 500 MHz				
		$V_{CC} = 2.3 V$	2	3	2	dBm
		$V_{CC} = 2.5 V$	4	4	3	dBm
		$V_{CC} = 2.7 V$	5	5	4	dBm
		f = 750 MHz				
		$V_{CC} = 2.3 V$	2	2	1	dBm
		$V_{CC} = 2.5 V$	4	4	2	dBm
		$V_{CC} = 2.7 V$	5	4	3	dBm

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Symbol	Parameter	Conditions	T _{amb} (°C)			Unit
			-40	25	85	
P _{L(sat)}	saturated output power	f = 250 MHz				
		$V_{CC} = 2.3 V$	4	4	4	dBm
		V _{CC} = 2.5 V	5	5	5	dBm
		$V_{CC} = 2.7 V$	6	6	6	dBm
		f = 500 MHz				
		V _{CC} = 2.3 V	3	3	3	dBm
		V _{CC} = 2.5 V	4	4	4	dBm
		$V_{CC} = 2.7 V$	5	5	5	dBm
		f = 750 MHz				
		$V_{CC} = 2.3 V$	3	3	2	dBm
		V _{CC} = 2.5 V	4	4	3	dBm
		$V_{CC} = 2.7 V$	5	5	4	dBm

Table 11.Saturated output power over temperature and supply voltagesTypical values.

Table 12.	Second-order intermodulation distance over temperature and supply voltages
Typical val	ues.

Symbol	Parameter	Conditions	Tamb	T _{amb} (°C)		Unit
			-40	25	85	
∆IM2	second-order intermodulation distance	$f_1 = 250 \text{ MHz};$ $f_2 = 251 \text{ MHz};$ $P_{drive} = -35 \text{ dBm}$				
1		V _{CC} = 2.3 V	31	27	25	dBc
		V _{CC} = 2.5 V	29	27	25	dBc
		V _{CC} = 2.7 V	29	28	26	dBc
		$f_1 = 500 \text{ MHz};$ $f_2 = 501 \text{ MHz};$ $P_{drive} = -35 \text{ dBm}$				
		V _{CC} = 2.3 V	27	25	23	dBc
		V _{CC} = 2.5 V	26	24	22	dBc
l		V _{CC} = 2.7 V	25	24	22	dBc

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Symbol	Parameter	Conditions	T _{amb} (°C)			Unit
			-40	25	85	
IP3 ₀	output third-order intercept point	$f_1 = 250 \text{ MHz};$ $f_2 = 251 \text{ MHz};$ $P_{drive} = -38 \text{ dBm}$				
		V _{CC} = 2.3 V	13	13	13	dBm
		V _{CC} = 2.5 V	15	15	15	dBm
		$V_{CC} = 2.7 V$	17	16	16	dBm
		$f_1 = 500 \text{ MHz};$ $f_2 = 501 \text{ MHz};$ $P_{drive} = -38 \text{ dBm}$				
		V _{CC} = 2.3 V	13	13	12	dBm
		$V_{CC} = 2.5 V$	15	14	13	dBm
		$V_{CC} = 2.7 V$	16	15	14	dBm
		$f_1 = 750 \text{ MHz};$ $f_2 = 751 \text{ MHz};$ $P_{drive} = -38 \text{ dBm}$				
		V _{CC} = 2.3 V	13	12	11	dBm
		V _{CC} = 2.5 V	14	13	11	dBm
		V _{CC} = 2.7 V	15	14	12	dBm

Table 13. Output third-order intercept point over temperature and supply voltages Typical values. Values.

Table 14. -3 dB bandwidth over temperature and supply voltages Typical values.

Symbol	Parameter	Conditions	T _{amb} (°	T _{amb} (°C)		
			-40	25	85	
B _{-3dB}	–3 dB bandwidth	V _{CC} = 2.3 V	2.19	2.09	1.96	GHz
		V _{CC} = 2.5 V	2.12	2.05	1.91	GHz
		V _{CC} = 2.7 V	2.07	2.00	1.87	GHz

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9. Test information

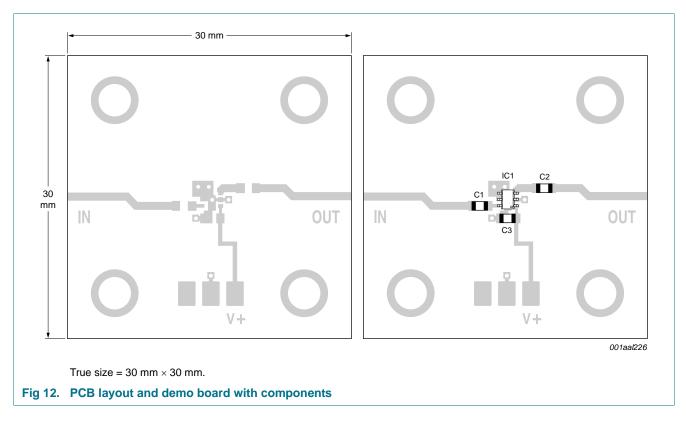


Table 15. List of components used for the typical application

Component	Description	Value	Dimensions
C1, C2	multilayer ceramic chip capacitor	100 pF	0603
C3	multilayer ceramic chip capacitor	22 nF	0603
IC1	BGA2870 MMIC		SOT363

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10. Package outline

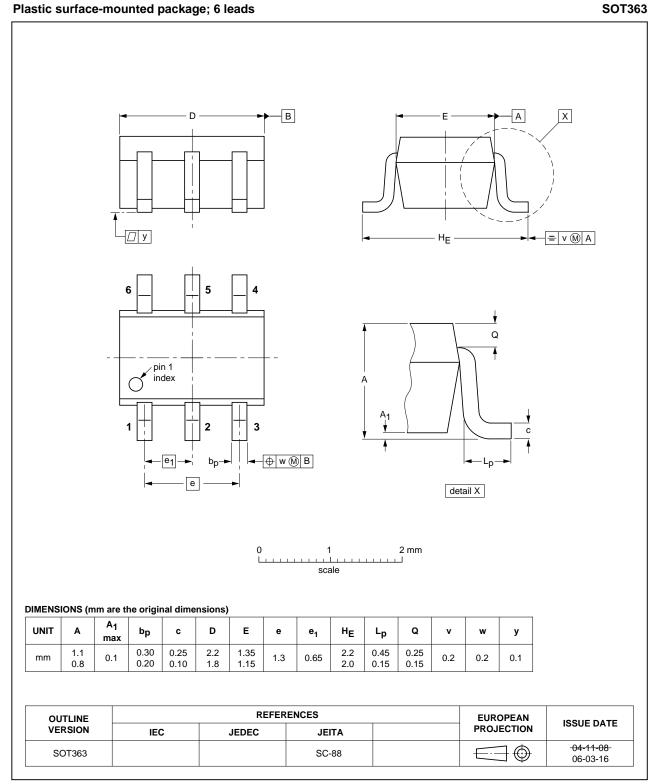


Fig 13. Package outline SOT363

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11. Abbreviations

Table 16. Abbreviations				
Acronym	Description			
DC	Direct Current			
IF	Intermediate Frequency			
LNA	Low-Noise Amplifier			
LNB	Low-Noise Block converter			
PCB	Printed-Circuit Board			
RF	Radio Frequency			
SMD	Surface Mounted Device			

12. Revision history

Table 17. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BGA2870 v.3	20150713	Product data sheet	-	BGA2870 v.2
Modifications:	 The format of this data sheet has been redesigned to comply with the new identity guideling of NXP Semiconductors. Legal texts have been adapted to the new company name where appropriate. 			
BGA2870 v.2	20110429	Product data sheet	-	BGA2870 v.1
BGA2870 v.1	20110224	Product data sheet	-	-

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Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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Product [short] data sheet	Production	This document contains the product specification.

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